

Feb. 2005

U	Inventor	Document	Issue P	Title	Current	Current X	Retrieval	S	C	P	Image	Doc	P
1	Ransbey, US	654181	2003	2 Planar structure for non-volatile memo	257/32	257/E21.6						US 654181	
2	Yoshino, A	US 200401	2004	2 Nonvolatile semiconductor memory de	257/31							US 200401	
3	Lee, Chang	US 200500	2005	2 Nonvolatile memory devices and meth	438/25	438/265						US 200500	
4	Moriya, Hir	US 200500	2005	2 NON-VOLATILE SEMICONDUCTOR M	438/26							US 200500	
5	Lee, Chang	US 200301	2003	2 Nonvolatile memory devices and meth	365/20	257/E21.6						US 200301	
6	Torii, Satou	US 200300	2003	4 Non-volatile semiconductor memory a	257/31	257/E21.6						US 200300	
7	Moriya, Hir	US 200300	2003	2 Nonvolatile semiconductor storage de	365/20	257/E21.6						US 200300	
8	Lee, Chang	US 200300	2003	1 Method of forming non-volatile memor	438/25							US 200300	
9	Goda, Akir	US 200300	2003	8 Semiconductor device and method of	257/49	257/E21.5						US 200300	
10	Ransbey, US	200201	2002	2 Simultaneous formation of charge stor	438/25	257/E21.6						US 200201	